Docket No.: 21302/0204309-US0

(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Euijoon Yoon et al.

Application No.: 10/596,126

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Filed: May 31, 2006

For: GROWTH METHOD OF NITRIDE

SEMICONDUCTOR LAYER AND LIGHT EMITTING DEVICE USING THE GROWTH

METHOD

Confirmation No.: 2554

Art Unit: 2813

Examiner: Crawford, LaTanya N.

RESPONSE TO NON-FINAL OFFICE ACTION

MS Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INTRODUCTORY COMMENTS

Dear Sir:

In response to the Non-Final Office Action dated March 2, 2009, please amend the above-identified U.S. patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 7 of this paper.